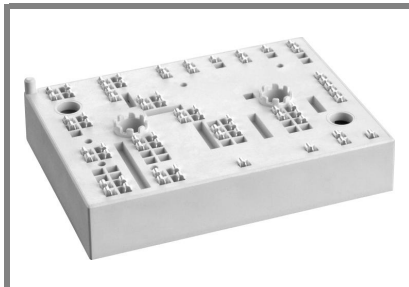


SKiIP 36NAB126V1



MiniSKiIP[®] 3

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiIP 36NAB126V1

Features

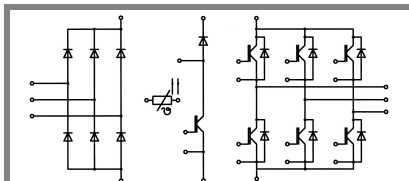
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 36 kVA
- Typical motor power 18,5 kW

Remarks

- V_{CEsat} , V_F = chip level value



NAB

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values	Units	
IGBT - Inverter, Chopper				
V_{CES}	$T_s = 25 (70)^\circ\text{C}$	1200	V	
I_C		88 (66)	A	
I_{CRM}		140	A	
V_{GES}		± 20	V	
T_j		- 40 ... + 150	$^\circ\text{C}$	
Diode - Inverter, Chopper				
I_F	$T_s = 25 (70)^\circ\text{C}$	91 (68)	A	
I_{FRM}		140	A	
T_j		- 40 ... + 150	$^\circ\text{C}$	
Diode - Rectifier				
V_{RRM}	$T_s = 70^\circ\text{C}$	1600	V	
I_F		61	A	
I_{FSM}		$t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$	700	A
i^2t		$t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$	2400	A^2s
T_j		- 40 ... + 150	$^\circ\text{C}$	
Module				
I_{RMS}	per power terminal (20 A / spring)	80	A	
T_{stg}		- 40 ... + 125	$^\circ\text{C}$	
V_{isol}	AC, 1 min.	2500	V	

Characteristics		$T_s = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
V_{CEsat}	$I_{Cnom} = 70 \text{ A}, T_j = 25 (125)^\circ\text{C}$		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 3 \text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25 (125)^\circ\text{C}$		1 (0,9)	1,2 (1,1)	V
r_T	$T_j = 25 (125)^\circ\text{C}$		10 (16)	13 (19)	$\text{m}\Omega$
C_{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		4,8		nF
C_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		1		nF
C_{res}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,6		nF
$R_{th(j-s)}$	per IGBT		0,5		K/W
$t_{d(on)}$	under following conditions		80		ns
t_r	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		25		ns
$t_{d(off)}$	$I_{Cnom} = 70 \text{ A}, T_j = 125^\circ\text{C}$		390		ns
t_f	$R_{Gon} = R_{Goff} = 9 \Omega$		90		ns
E_{on}	inductive load		9		mJ
E_{off}			7,7		mJ
Diode - Inverter, Chopper					
$V_F = V_{EC}$	$I_{Fnom} = 70 \text{ A}, T_j = 25 (125)^\circ\text{C}$		1,5 (1,5)	1,7 (1,7)	V
$V_{(TO)}$	$T_j = 25 (125)^\circ\text{C}$		1 (0,8)	1,1 (0,9)	V
r_T	$T_j = 25 (125)^\circ\text{C}$		7,1 (10)	8,6 (11)	$\text{m}\Omega$
$R_{th(j-s)}$	per diode		0,7		K/W
I_{RRM}	under following conditions		77		A
Q_{rr}	$I_{Fnom} = 70 \text{ A}, V_R = 600 \text{ V}$		18		μC
E_{rr}	$V_{GE} = 0 \text{ V}, T_j = 125^\circ\text{C}$ $di_F/dt = 2000 \text{ A}/\mu\text{s}$		7,5		mJ
Diode - Rectifier					
V_F	$I_{Fnom} = 35 \text{ A}, T_j = 25^\circ\text{C}$		1,1		V
$V_{(TO)}$	$T_j = 150^\circ\text{C}$		0,8		V
r_T	$T_j = 150^\circ\text{C}$		11		$\text{m}\Omega$
$R_{th(j-s)}$	per diode		0,9		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25 (100)^\circ\text{C}$		1000(1670)		Ω
Mechanical Data					
w			95		g
M_s	Mounting torque	2		2,5	Nm

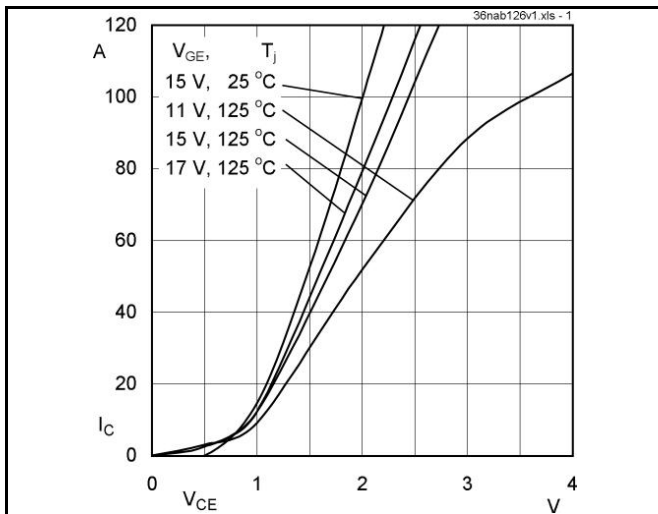


Fig. 1 Typ. output characteristic

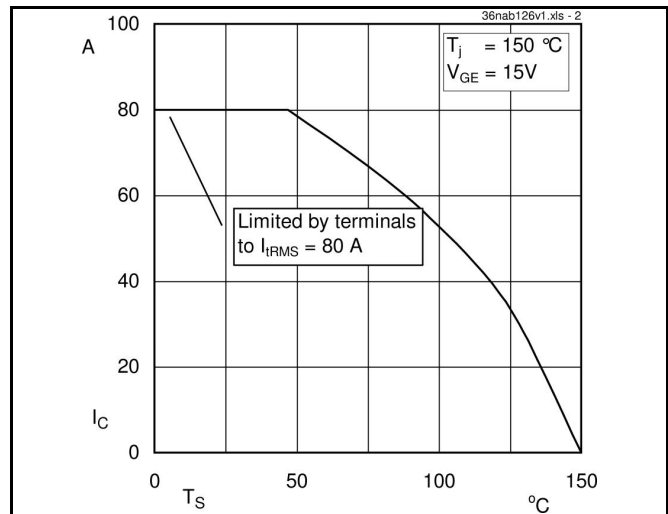


Fig. 2 Typ. rated current vs. temperature

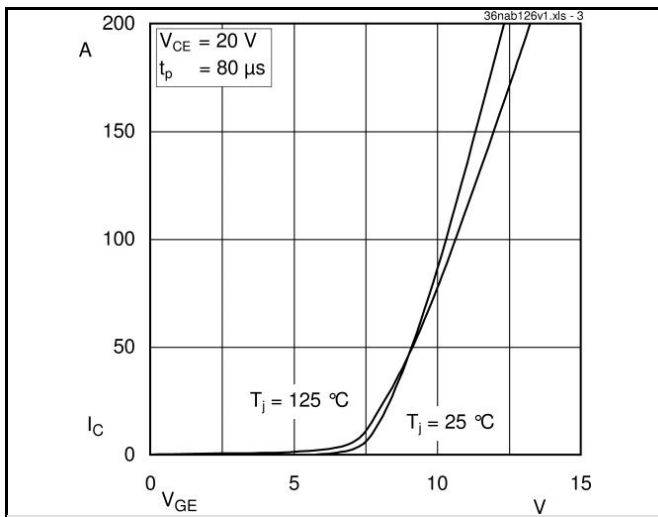


Fig. 3 Typ. transfer characteristic

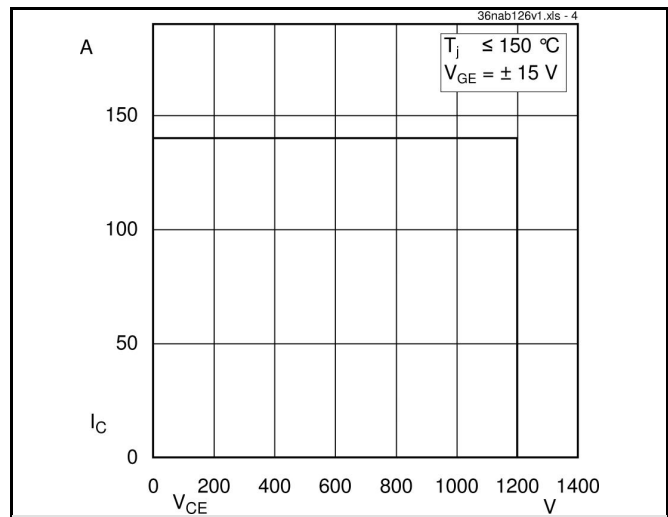


Fig. 4 Reverse bias safe operating area

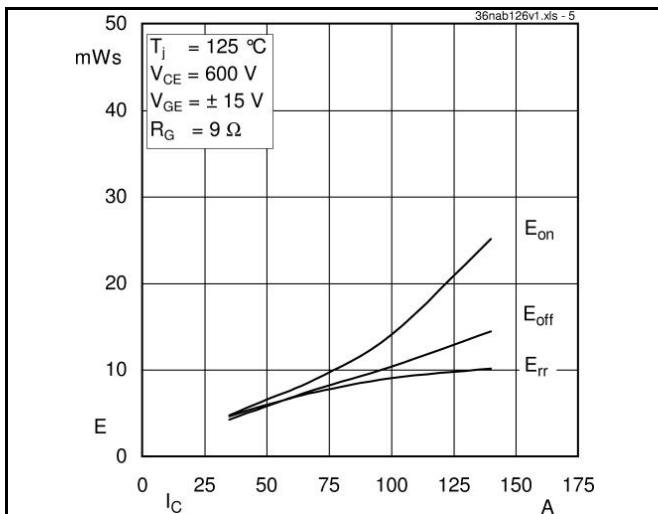


Fig. 5 Typ. Turn-on /-off energy = $f(I_C)$

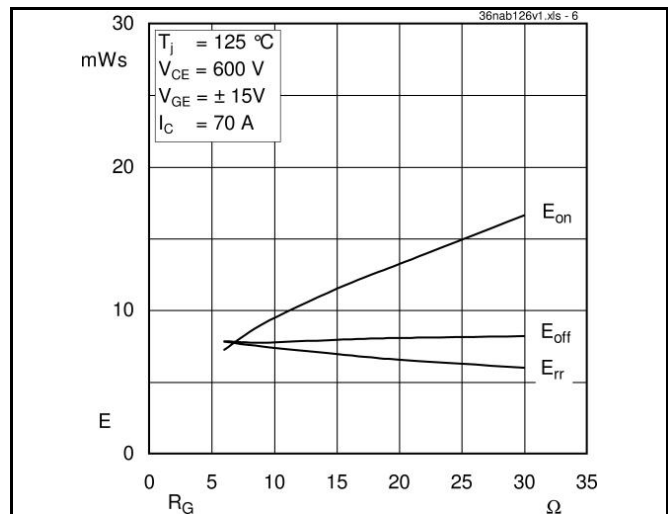


Fig. 6 Typ. Turn-on /-off energy = $f(R_G)$

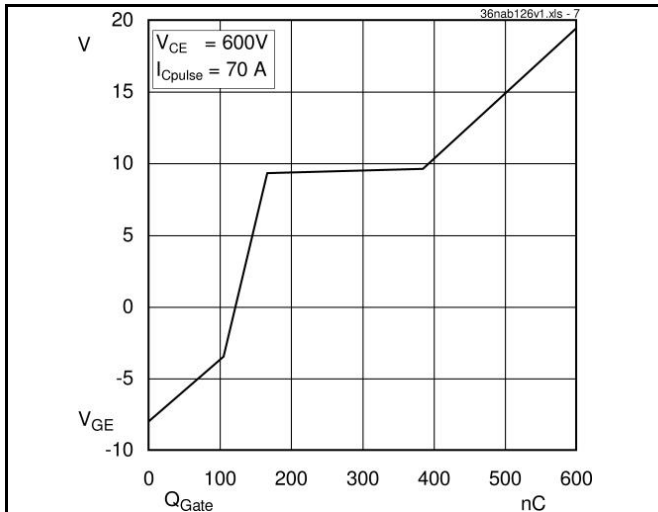


Fig. 7 Typ. gate charge characteristic

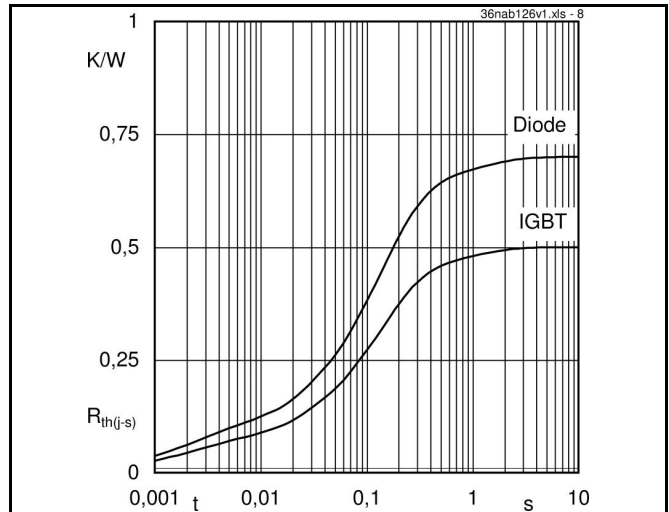


Fig. 8 Typ. thermal impedance

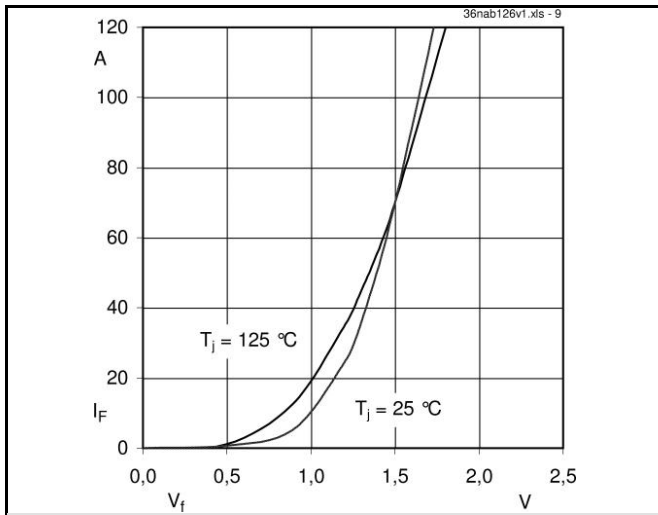


Fig. 9 Typ. freewheeling diode forward characteristic

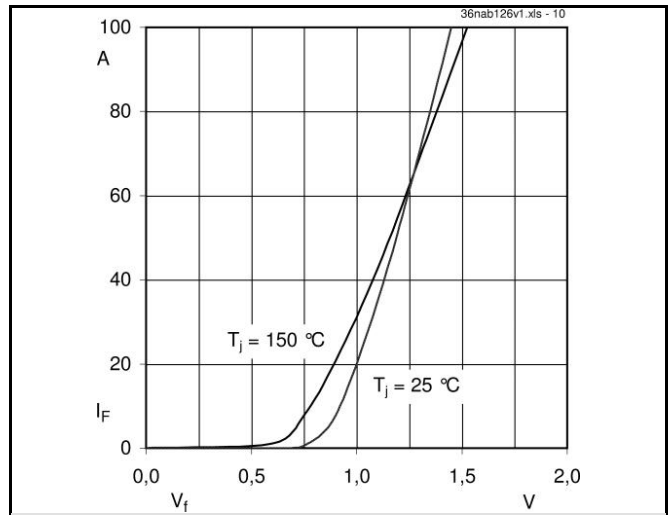


Fig. 10 Typ. input bridge forward characteristic

